MBR10XXCT SERIES SCHOTTKY BARRIER RECTIFIER

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MBR1035CT THRU MBR10200CT

SCHOTTKY BARRIER RECTIFIER





REVERSE VOLTAGE: FORWARD CURRENT:

35 to 200 VOLTS 10.0 AMPERE

FEATURES

- · Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- \cdot Metal silicon junction, majority carrier conduction
- · Guard ring for overvoltage protection
- · Low power loss, high efficiency
- · For use in low voltage,high frequency inverters,free whelling,and polarity protection applications
- · High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

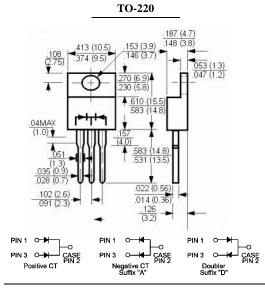
MECHANICAL DATA

Case: Molded plastic, TO-220

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202

method 208 guaranteed Polarity: As marked Mounting position: Any Weight: 0.08ounce, 2.24gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	MBR1035CT	MBR1045CT	MBR1050CT	MBR1060CT	MBR1080CT	MBR10100CT	MBR10150CT	MBR10200CT	Units	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	80	100	150	200	Volts	
Maximum RMS Voltage	V_{RMS}	24	31	35	42	56	70	105	140	Volts	
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	80	100	150	200	Volts	
Maximum Average Forward Rectified Current at $T_{\rm C}$ = 105°C	$I_{(AV)}$	10.0							Amp		
Peak repetitive forward current at $T_C = 105$ °C (rated VR, sq. wave, 20 KHz)	I_{FRM}	10.0								Amp	
Peak Forward Surge Current,											
8.3ms single half-sine-wave	I_{FSM} 125								Amp		
superimposed on rated load (JEDEC method)											
Peak repetitive reverse current at tp = 2.0μs, 1KHz	I_{RRM}	1.0 0.5						Amp			
at $I_F = 5.0A$, $T_C = 25^{\circ}C$	$\mathbf{V_F}$	0.7	70	0.3	30	0.8	85	0.9	95	Volts	
Maximum Forward at $I_F = 5.0A$, $T_C = 125^{\circ}C$		0.	57	0.0	55	0.7	75	0.3	85		
Voltage (Note 1) at $I_F = 10A$, $T_C = 25^{\circ}C$		0.8	80	0.9	90	0.	95	0.	98		
at $I_F = 10A$, $T_C = 125^{\circ}C$		0.0	67	0.7	75	0.	85	0.	88		
Maximum Reverse Current at T _C =25℃	т	0.1								A	
at Rated DC Blocking Voltage T _C =125℃	I_R	1	.5	1	0	2	2		5	mAmp	
Typical Thermal Resistance	$R_{\theta JC}$	1.5							°C/W		
Operating Temperature Range	T_{J}	-55 to +150								r	
Storage Temperature Range	Tstg	-55 to +150								${\mathfrak C}$	

NOTES:

1- Pulse test: 300µs pulse width, 1% duty cycle

MBR1035CT THRU MBR10200CT



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RATINGS AND CHARACTERISTIC CURVES

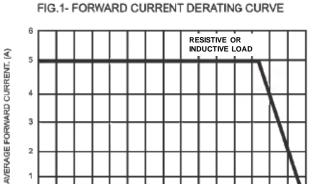


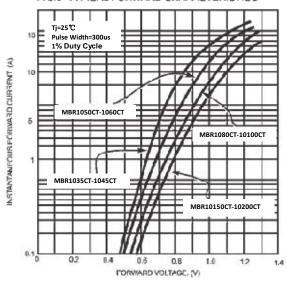
FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT 180 PEAK FORWARD SURGE CURRENT. (A) Ti=Ti max. 150 8.3ms Single Half Sine Wave JEDEC Method 120 90 60 30 0.1 NUMBER OF CYCLES AT 60Hz

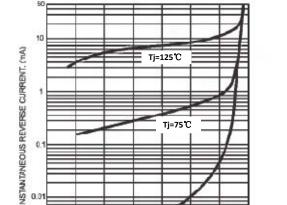


CASE TEMPERATURE. (°C)

150

50





PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Tj=25℃

0.0

FIG.4-TYPICAL REVERSE CHARACTERISTICS

